



JRW

PATENT  
Customer No. 22,852  
Attorney Docket No. 04329.3140

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of: )  
Takashi YODA et al. ) Group Art Unit: 2814  
Application No.: 10/663,799 ) Examiner: Cao, Phat X.  
Filed: September 17, 2003 ) Confirmation No. 3768  
For: SEMICONDUCTOR DEVICE )  
WITH POROUS LAYER AND )  
CONDUCTIVE BARRIER LAYER )  
(AS AMENDED) )

**Mail Stop Amendment**  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

**AMENDMENT**

In reply to the Office Action mailed January 11, 2005, the period for response to which extends through April 11, 2005, please amend the application as follows.

**An Amendment to the Title** is set forth on page 2 of this paper.

**Amendments to the Claims** are reflected in the listing of claims beginning on page 3 of this paper.

**Remarks** begin on page 9 of this paper.

**AMENDMENT TO THE TITLE:**

Please amend the title of this application as follows:

~~SEMICONDUCTOR DEVICE AND METHOD OF MANUFACTURING THE SAME~~  
WITH POROUS LAYER AND CONDUCTIVE BARRIER LAYER